

Analog Electronic Circuits – Lab 6

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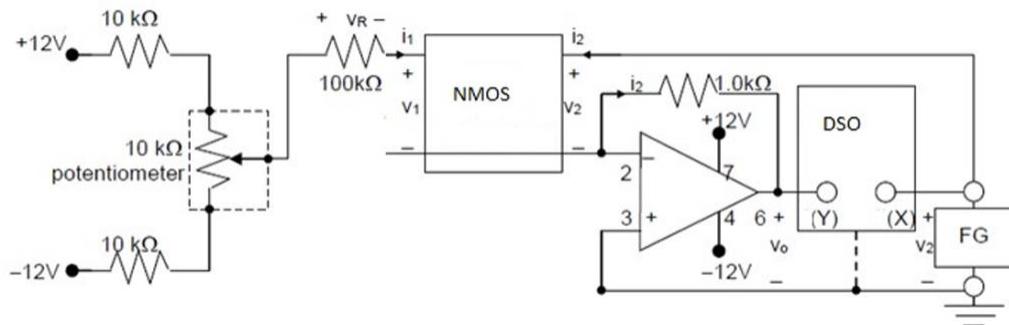
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Part 1:

- Objective:

To determine the I_D vs V_{DS} characteristics of the given MOSFET.

- Circuit:

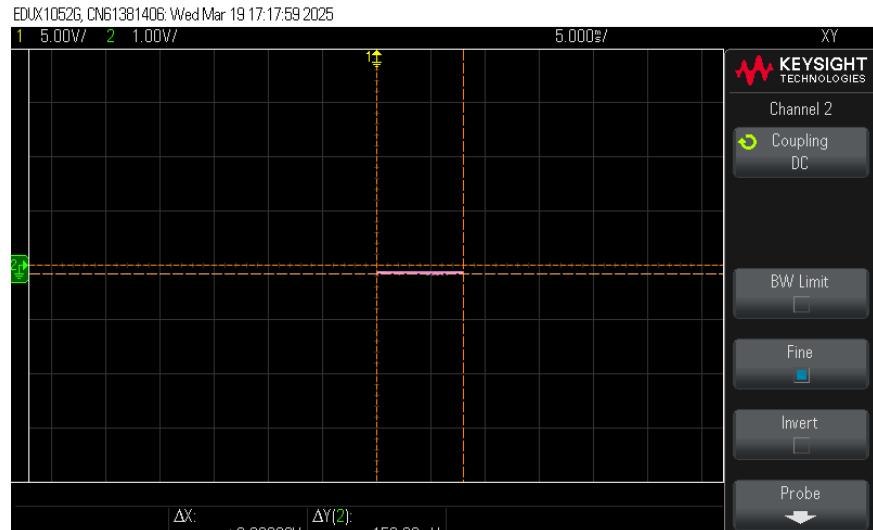


- Observations:

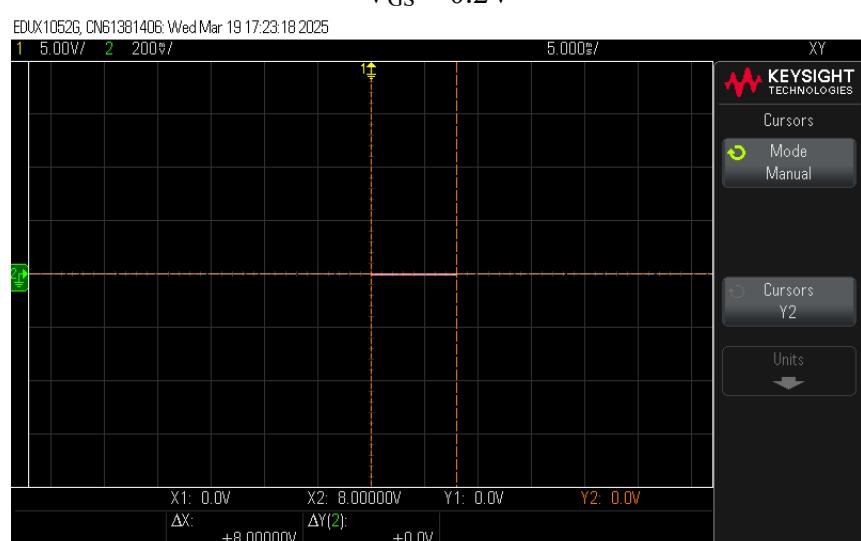
- V_{DS} varies from 0 to 8V using a sinusoid.

V_{GS}	V_{DS} Max	V_o	I_D	I_D Corrected
0.2	8	-0.15	-0.00015	0.00015
0.4	8	0	0	0
0.6	8	0	0	0
0.8	8	0	0	0
1	8	0	0	0
1.2	8	0	0	0
1.4	8	-0.0175	-0.0000175	0.0000175
1.6	8	-0.0475	-0.0000475	0.0000475
1.8	8	-0.115	-0.000115	0.000115
2	8	-0.2725	-0.0002725	0.0002725
3	8	-1.43375	-0.00143375	0.00143375
4	8	-3.0645	-0.0030645	0.0030645

I_D correction is required since the op-amp is in **Inverted** mode of operation, so the current value is multiplied by -1.

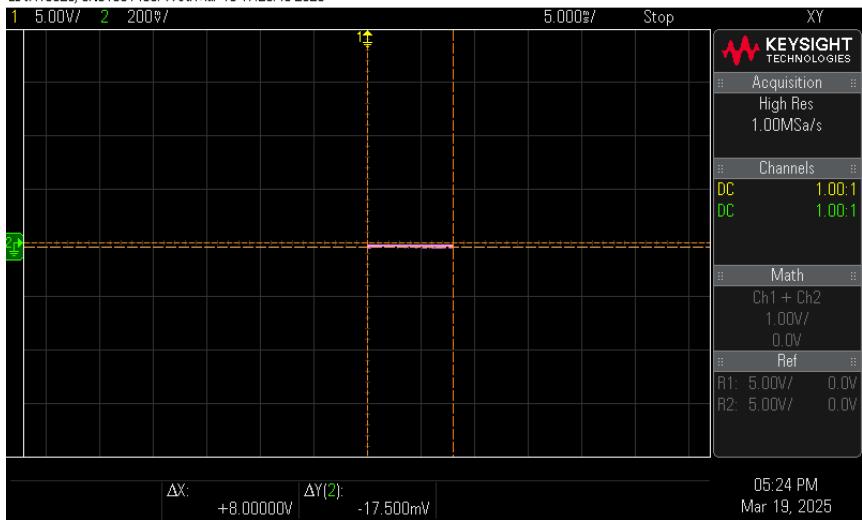


$$V_{GS} = 0.2V$$

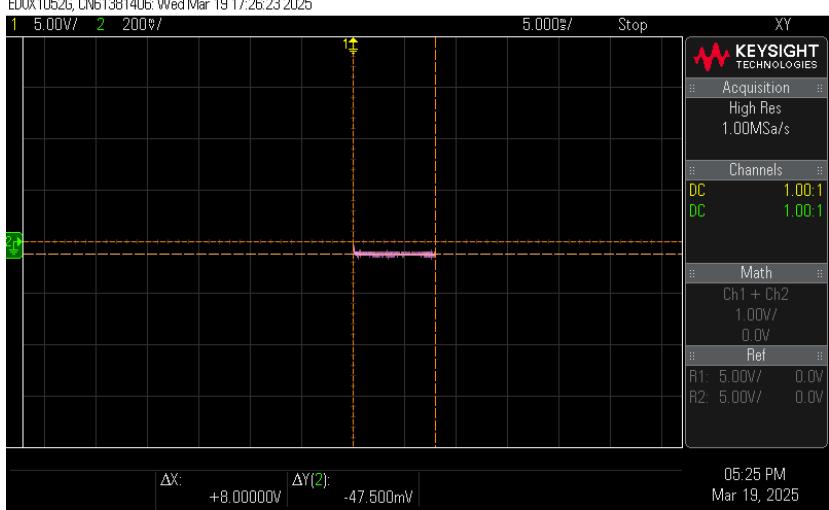


$$V_{GS} = 0.8V$$

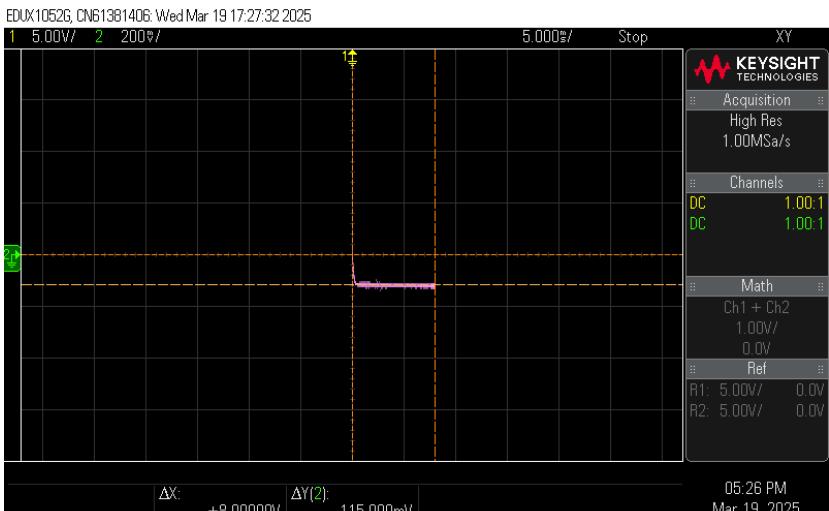
EDUX1052G, CN61381406; Wed Mar 19 17:25:48 2025



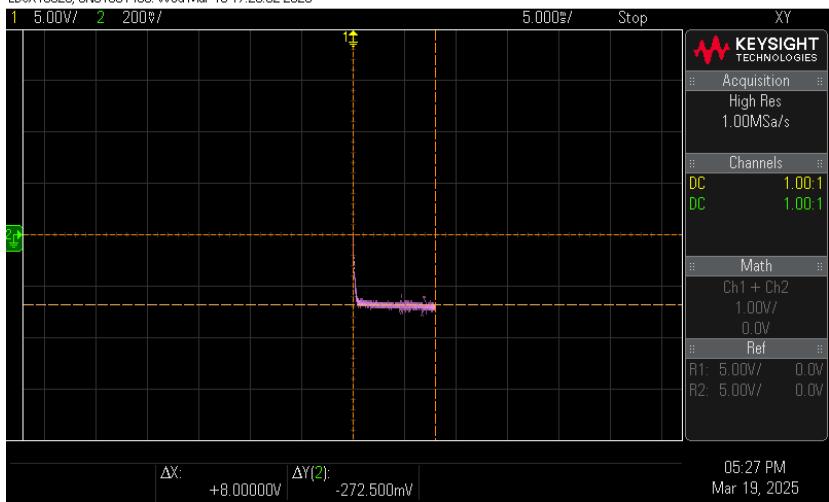
EDUX1052G, CN61381406; Wed Mar 19 17:26:23 2025



EDUX1052G, CN61381406; Wed Mar 19 17:27:32 2025

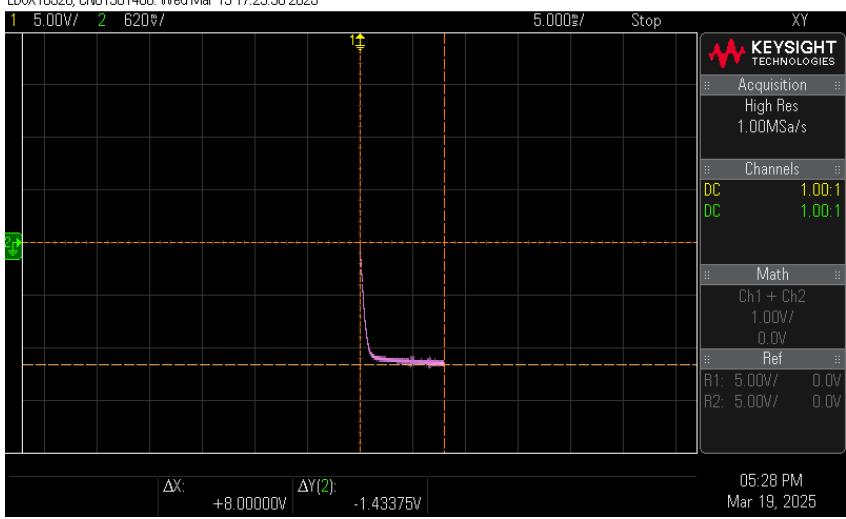


EDUX1052G, CN61381406 Wed Mar 19 17:28:32 2025



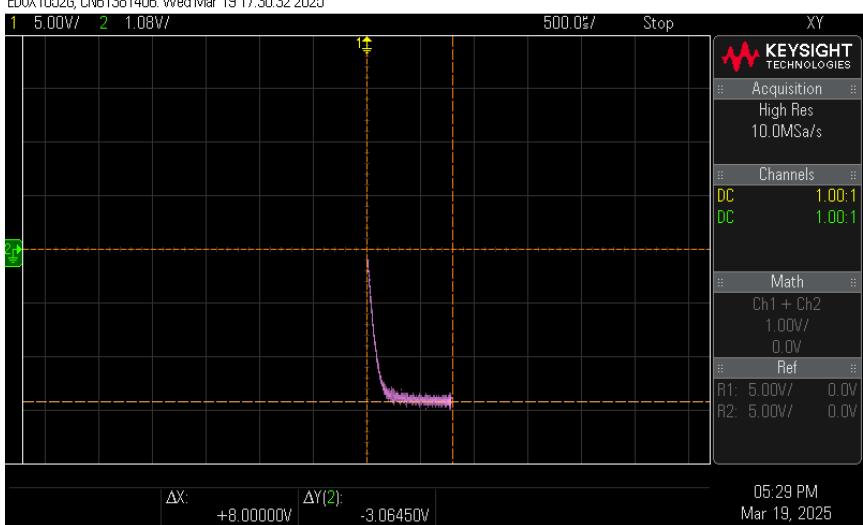
$$V_{GS} = 2V$$

EDUX1052G, CN61381406 Wed Mar 19 17:29:36 2025



$$V_{GS} = 3V$$

EDUX1052G, CN61381406 Wed Mar 19 17:30:32 2025

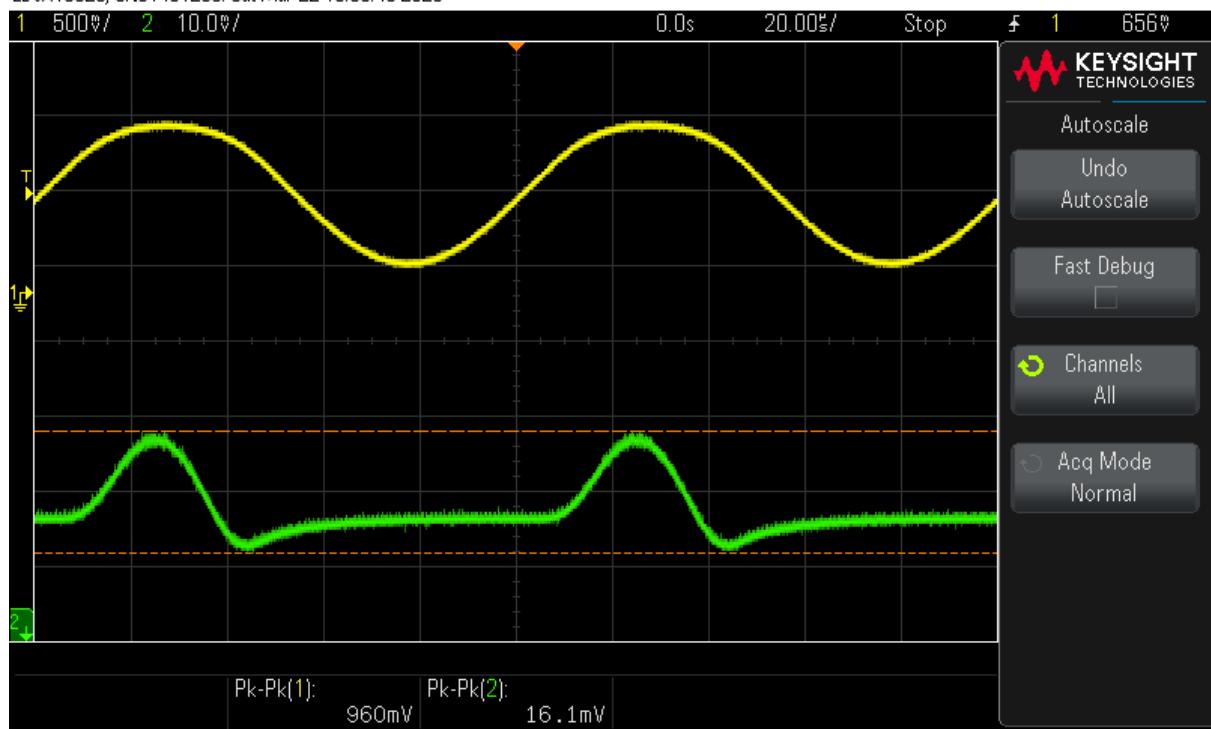


$$V_{GS} = 4V$$

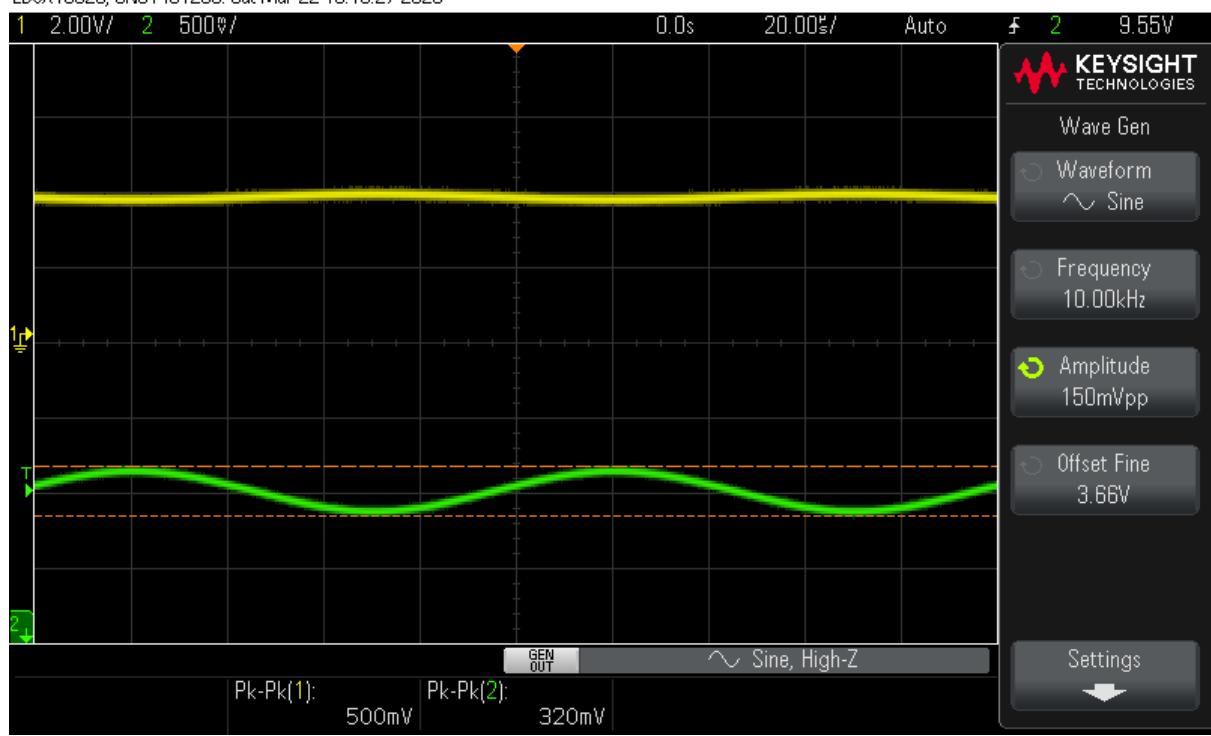
- Inference:

- The value of I_D begins to become significant at around $V_{GS} = 1.4$ V
- Therefore, the Threshold Voltage of the given MOSFET can be approximated to be around 1.4V.

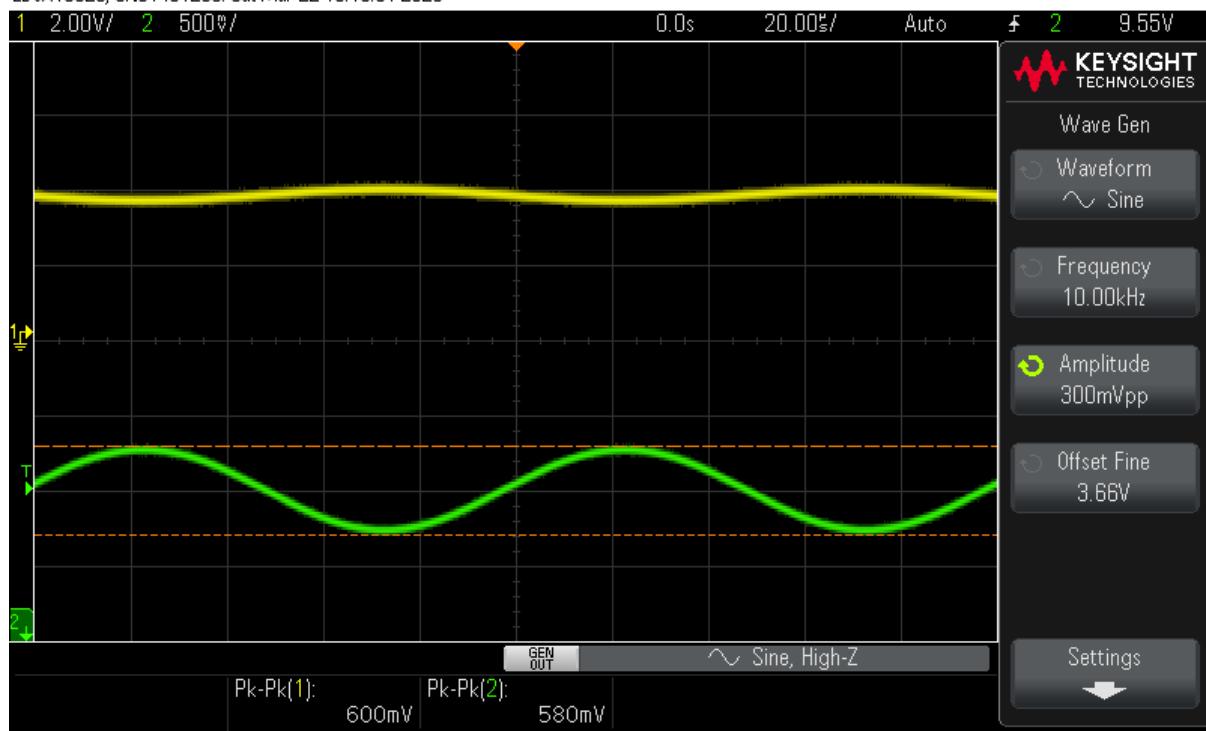
EDUX1052G, CN61431203: Sat Mar 22 18:00:40 2025



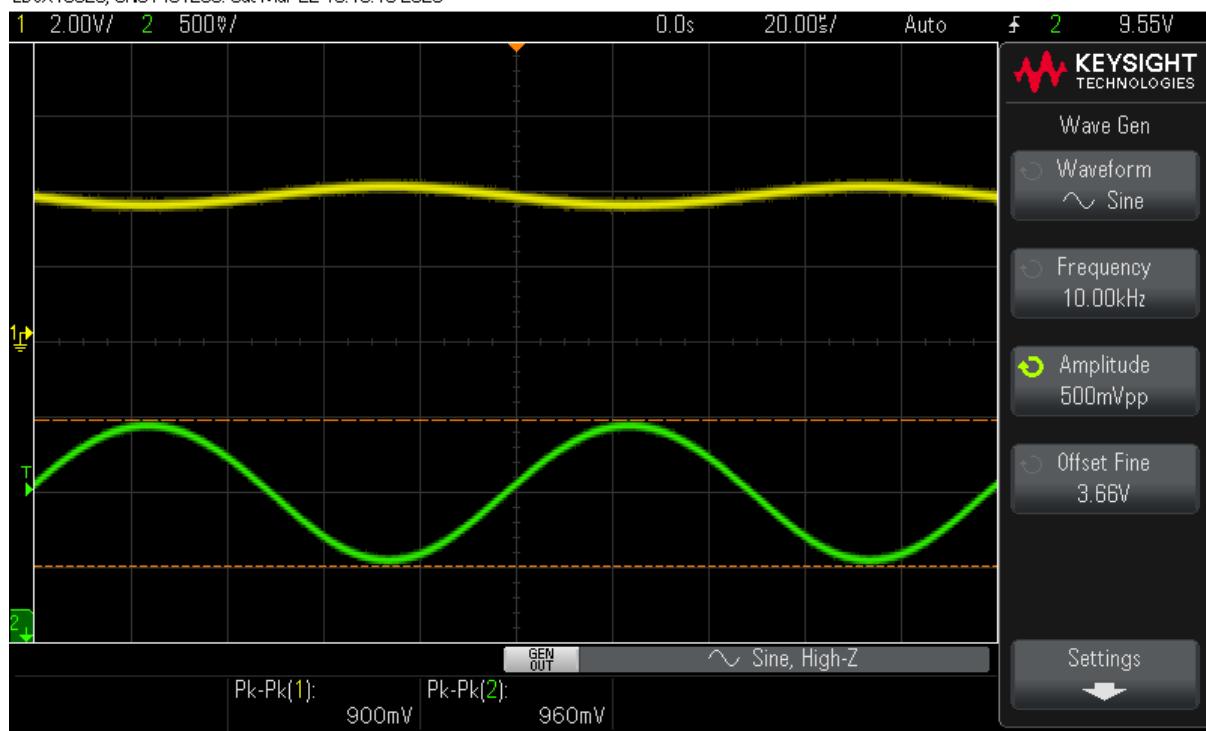
EDUX1052G, CN61431203: Sat Mar 22 18:18:27 2025

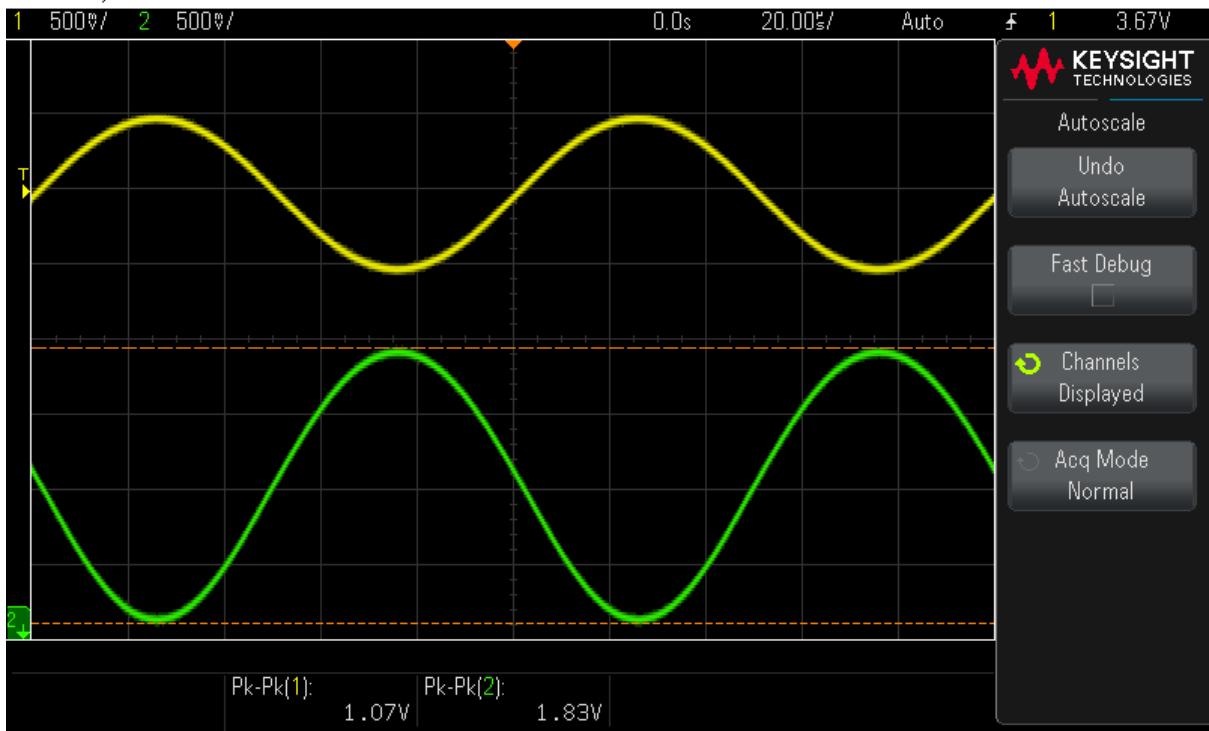


EDUX1052G, CN61431203: Sat Mar 22 18:19:01 2025



EDUX1052G, CN61431203: Sat Mar 22 18:19:15 2025





Part 2:

- Objective:

To determine the I_D vs V_{GS} characteristics and calculate the value of $\mu C_{ox} \frac{W}{L}$ of the given MOSFET.

- Circuit Diagram:

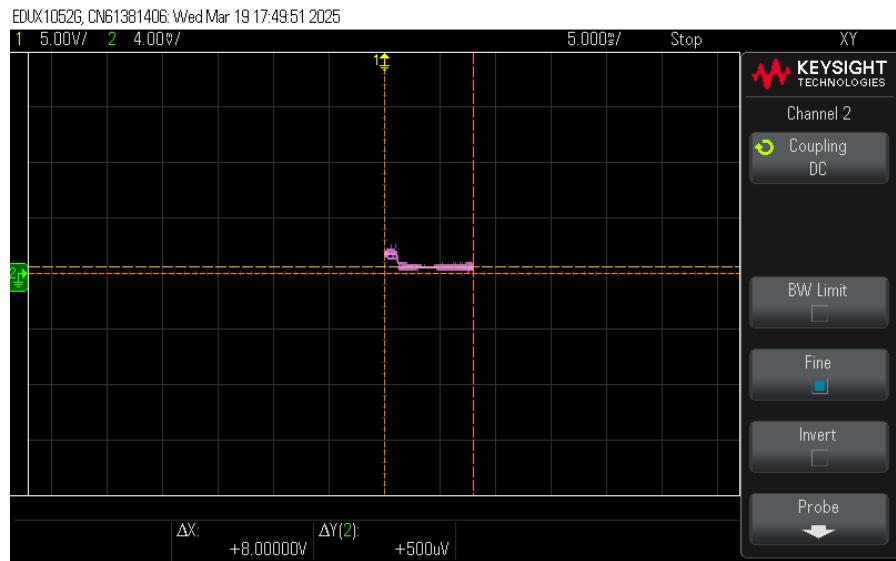
In the previous circuit, connect the potentiometer to the drain and the function generator to the gate of the MOSFET.

- Observation:

- V_{GS} is varied from 0 to 8V using a sinusoid.

V_{DS}	V_{GS}	V_O	I_D	I_D Corrected
0.1	8	5.00E-04	5.00E-07	-5.00E-07
0.5	8	-0.00975	-9.75E-06	9.75E-06
1	8	-0.0156	-1.56E-05	1.56E-05
2	8	-0.017	-1.70E-05	1.70E-05
3	8	-0.026	-2.60E-05	2.60E-05
4	8	-0.0335	-3.35E-05	3.35E-05

I_D correction is required since the op-amp is in **Inverted** mode of operation.
So, we multiply the current value by -1.

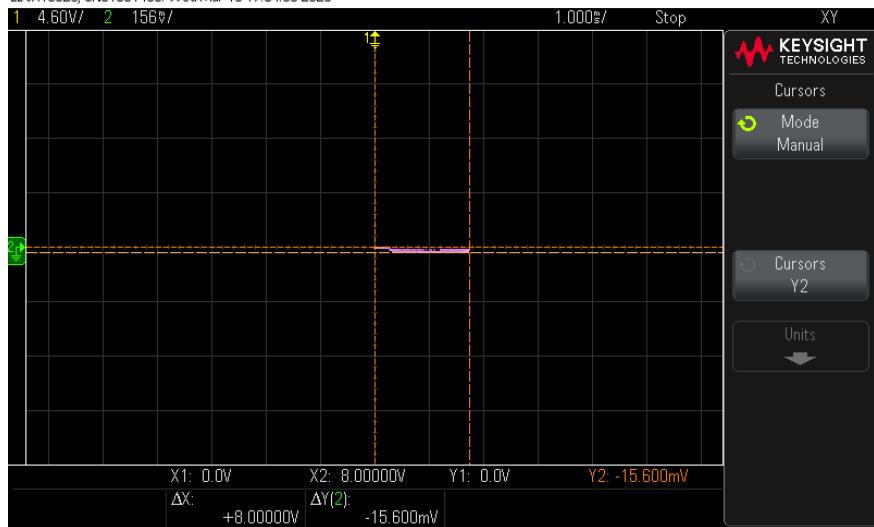


$$V_{DS} = 0.1V$$



$$V_{DS} = 0.5V$$

EDUX1052G, CN61381406; Wed Mar 19 17:54:06 2025



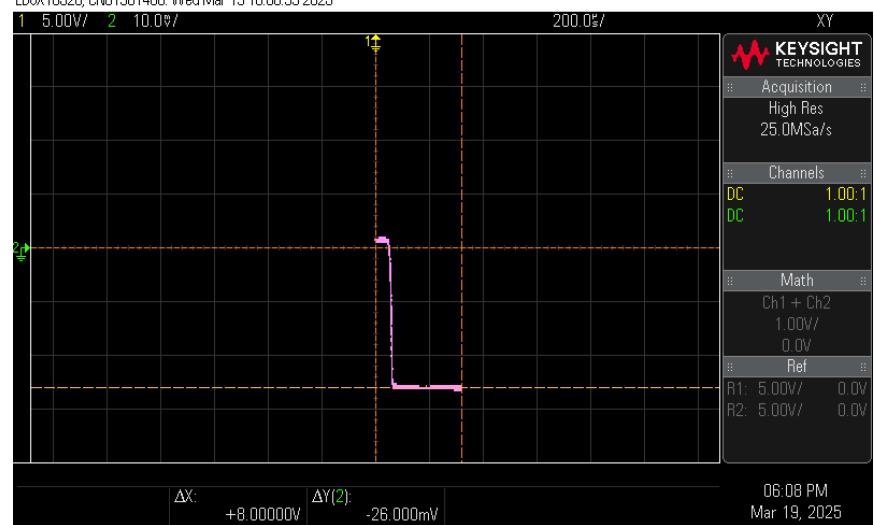
$$V_{DS} = 1V$$

EDUX1052G, CN61381406; Wed Mar 19 17:57:05 2025

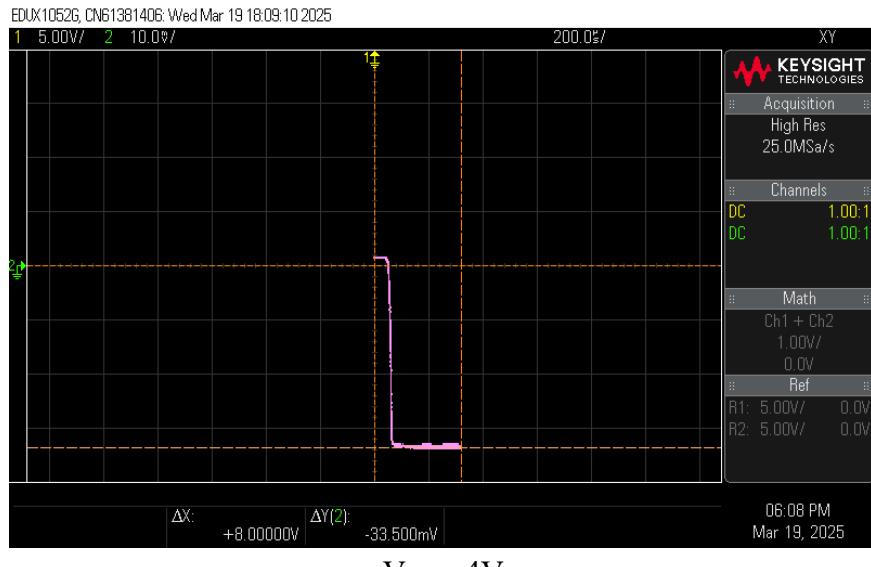


$$V_{DS} = 2V$$

EDUX1052G, CN61381406; Wed Mar 19 18:08:39 2025



$$V_{DS} = 3V$$



To find the parameters, we take $V_{DS} = 100$ mV, for linear region.

Point of Maximum Slope,

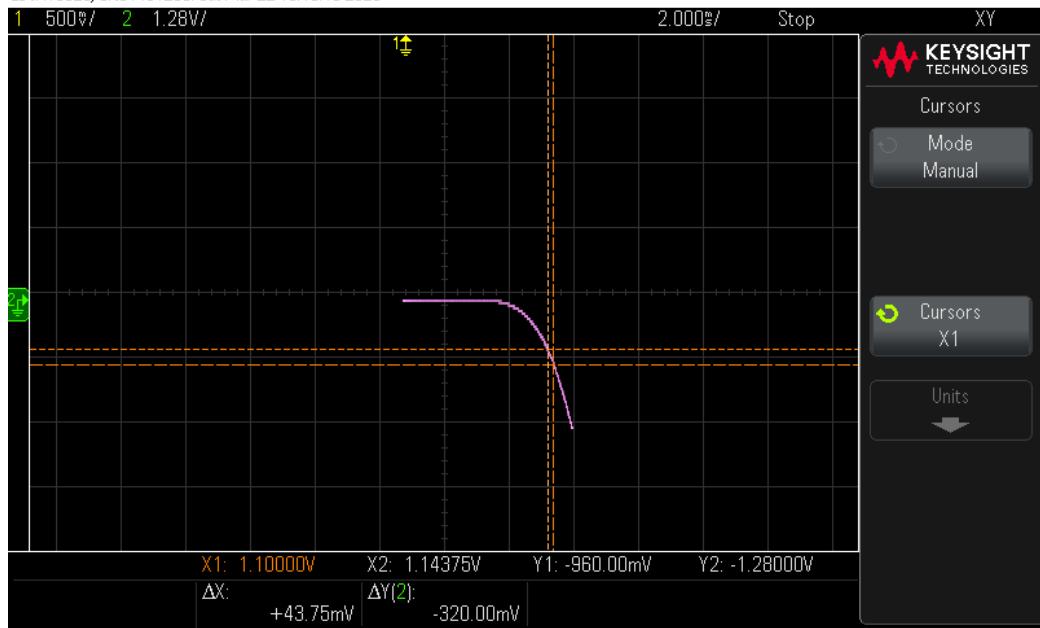


$$X (V_{GS}) = 1.14375 \text{ V}$$

$$Y (I_D) = (-1) \frac{-1.28}{1000} = 1.28mA$$

Slope,

EDUX1052G, CN61431203; Sat Mar 22 19:13:16 2025



$$m = \frac{\Delta y}{\Delta x} = 0.007314$$

$$\Rightarrow (0 - I_D) = m(V_T - V_{GS})$$

$$\Rightarrow V_T = \frac{-I_D}{m} + V_{GS}$$

$$\Rightarrow V_T = \frac{-1.28 \times 10^{-3}}{0.007314} + 1.14375$$

$$\Rightarrow V_T = 0.968743V$$

We know that,

$$I_D \approx \mu C_{ox} \frac{W}{L} (V_{GS} - V_T) V_{DS}$$

$$\Rightarrow \mu C_{ox} \frac{W}{L} = \frac{I_D}{(V_{GS} - V_T) V_{DS}}$$

$$\Rightarrow \mu C_{ox} \frac{W}{L} = \frac{1.28 \times 10^{-3}}{(1.14375 - 0.968743)(0.1)}$$

$$\Rightarrow \mu C_{ox} \frac{W}{L} = 0.07314 \text{ A/V}^2$$

- Inferences:

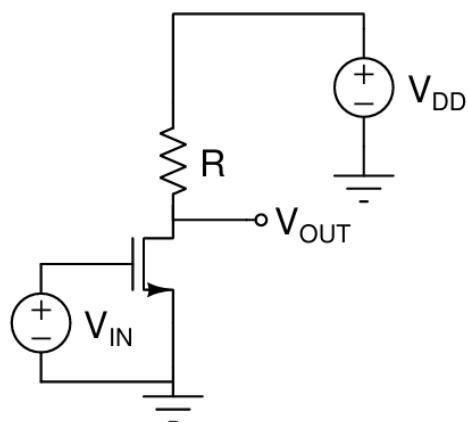
- $V_{TH} = 0.968743 \text{ V}$
- $\mu C_{ox} \frac{W}{L} = 0.07314 \text{ A/V}^2$

Part 3:

- Objective:

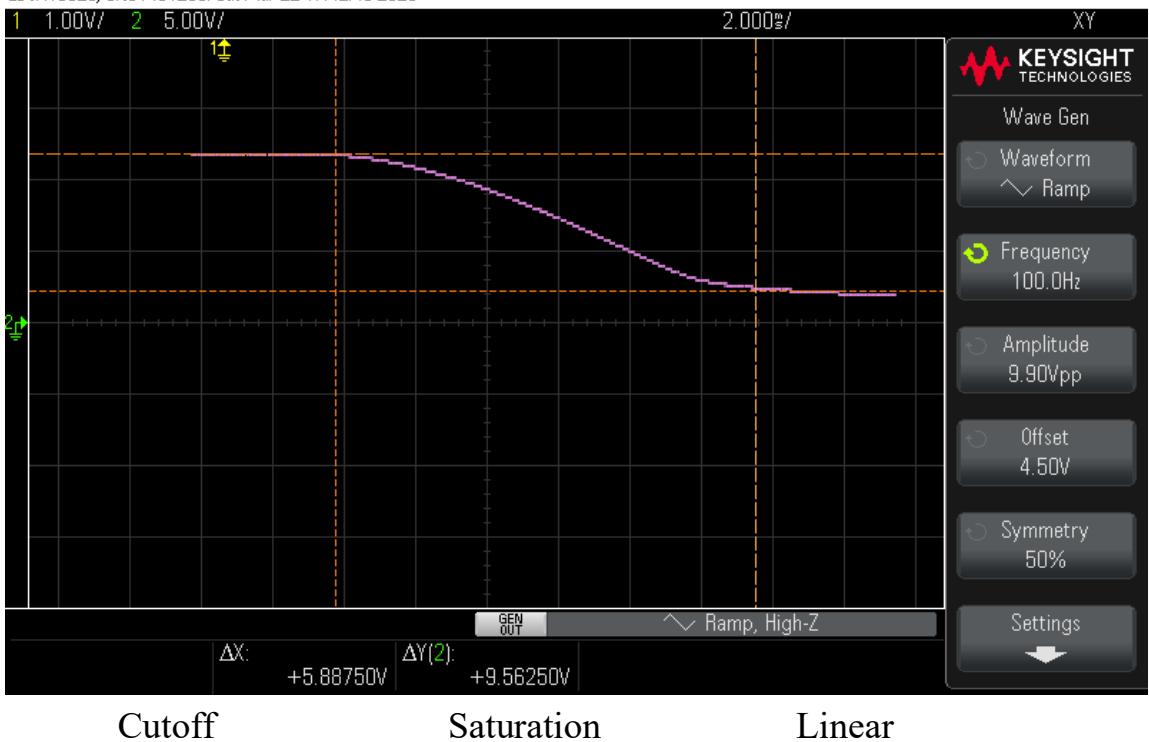
To perform Large Signal Analysis and find Voltage Transfer Characteristic of a MOS based Amplifier.

- Circuit Diagram:



- Observation:

EDUX1052G, CN61431203: Sat Mar 22 17:42:45 2025



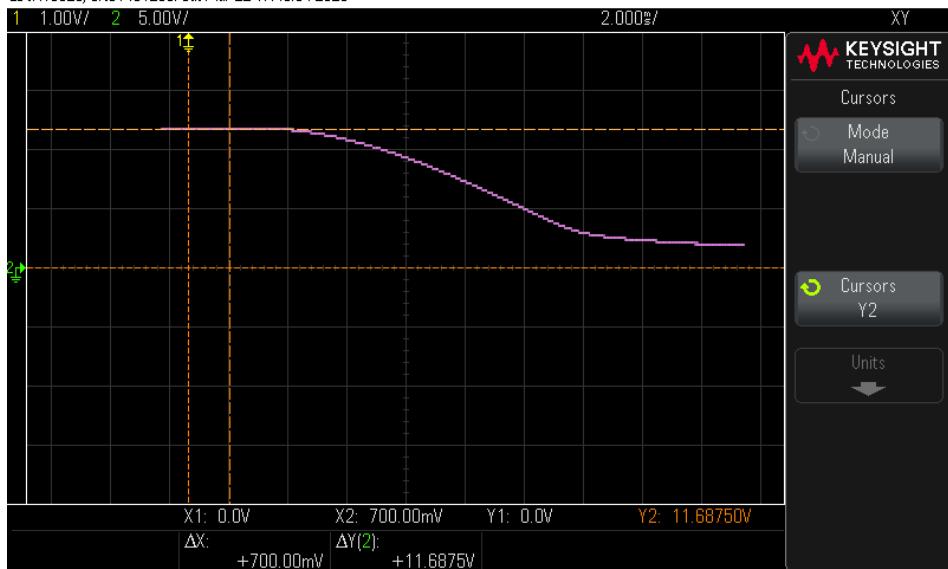
Cutoff

Saturation

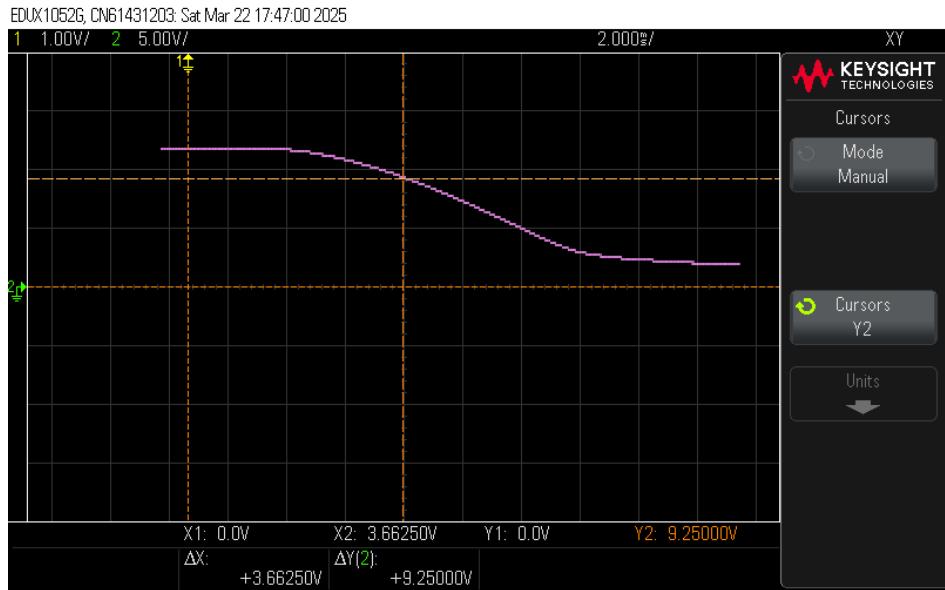
Linear

Mode	V _{in} (V)	V _{out} (V)
Cutoff	0.7	11.6875
Saturation	3.6625	9.25
Active	8.4125	2.0625

EDUX1052G, CN61431203: Sat Mar 22 17:46:04 2025



Cutoff



Saturation



Linear

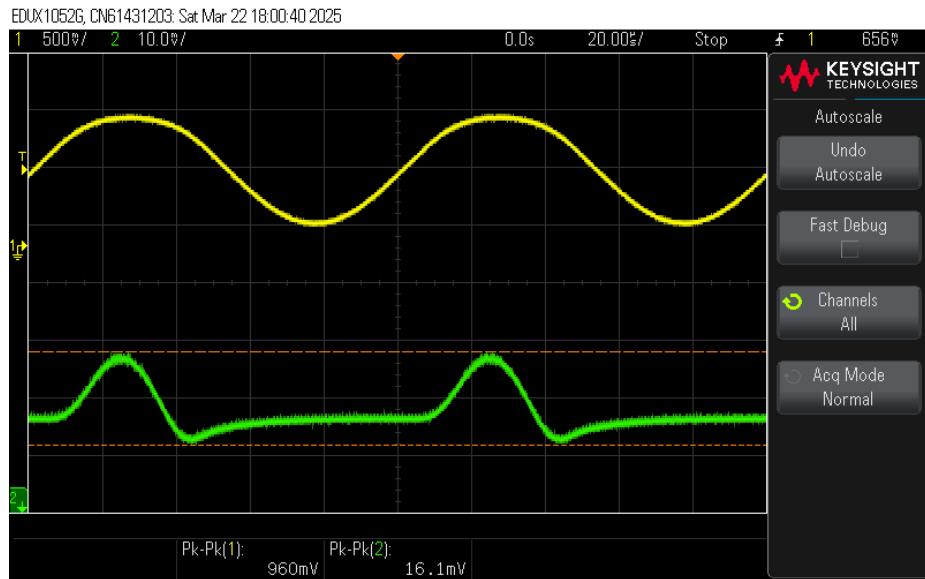
Applying Sinusoidal Signal with offset,

V _{DC}	V _{in}	V _{out}	Gain
0.7 (Cutoff)	0.05	0.6	12
0.7	0.1	0.6	6
0.7	0.5	0.6	1.2
0.7	1	0.0161	0.0161

3.6625 (Saturation)	0.15	0.32	2.133333
3.6625	0.3	0.58	1.933333
3.6625	0.5	0.96	1.92
3.6625	1	1.85	1.85

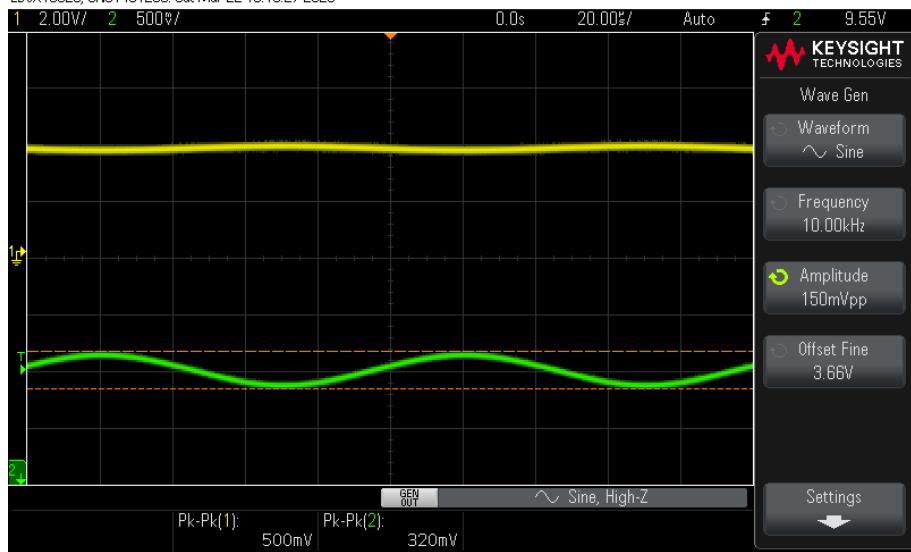
The values marked in red are wrong, since the output signal is too small for the probes to detect anything, so the measurement option of the DSO just measures noise.

For Linear mode, the DC offset is too high to set reasonable signal amplitude in the DSO.



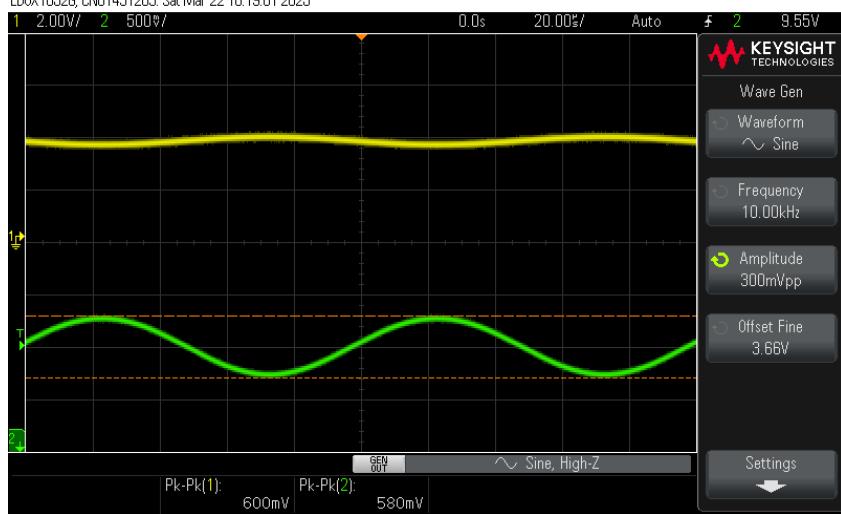
$$V_{DS} = 0.7, V_{in} = 1$$

EDUX1052G, CN61431203, Sat Mar 22 18:18:27 2025

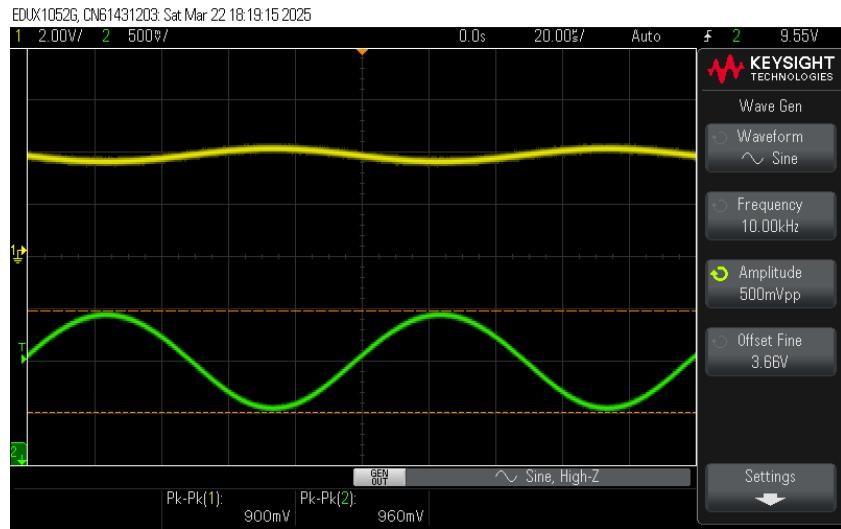


$$V_{DS} = 3.6625, V_{in} = 0.15$$

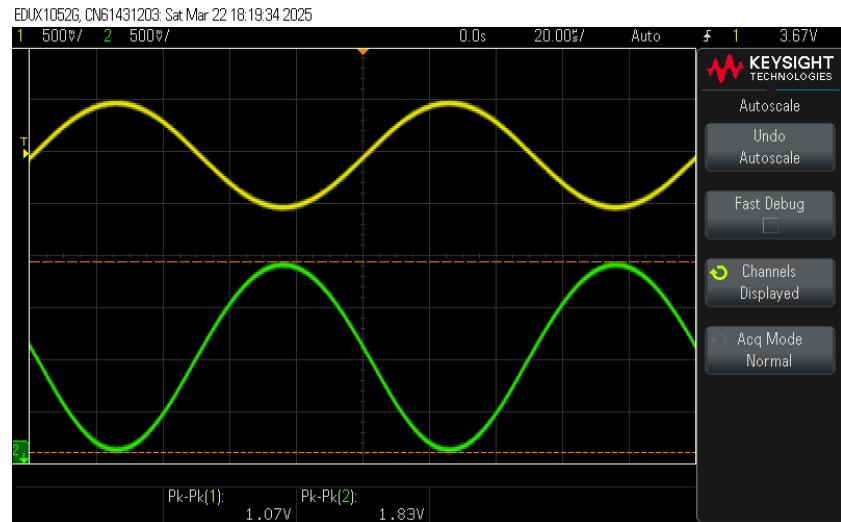
EDUX1052G, CN61431203, Sat Mar 22 18:19:01 2025



$$V_{DS} = 3.6625, V_{in} = 0.3$$



$$V_{DS} = 3.6625, V_{in} = 0.5$$



$$V_{DS} = 3.6625, V_{in} = 1$$

- Inferences:

The gain of the amplifier in normal operation (Saturation mode) is around 2.